



# DSR1A THRU DSR1M

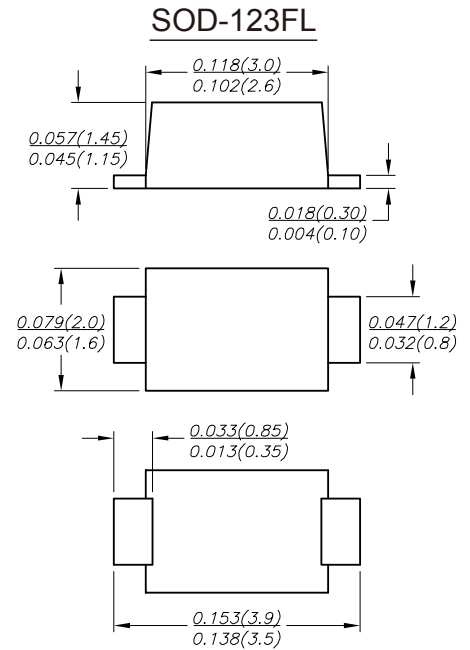
1.0 AMP Surface Mount General Purpose Silicon Rectifiers

## FEATURES

- Glass passivated device
- Ideal for surface mounted applications
- Low reverse leakage
- Metallurgically bonded construction
- High temperature soldering guaranteed:  
260°C/10 seconds, 0.375" (9.5mm) lead length,  
5 lbs. (2.3kg) tension

## MECHANICAL DATA

- Case:** SOD-123FL molded plastic body over passivated chip
- Terminals:** Plated axial leads, solderable per MIL-STD-750, Method 2026
- Polarity:** Color band denotes cathode end
- Mounting Position:** Any
- Weight:** 0.0007 ounce, 0.02 grams



## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

	SYMBOLS	DSR1A	DSR1B	DSR1D	DSR1G	DSR1J	DSR1K	DSR1M	UNITS
		S1A	S1B	S1D	S1G	S1J	S1K	S1M	
Maximum repetitive peak reverse voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS voltage	$V_{RMS}$	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	$V_{DC}$	50	100	200	400	600	800	1000	V
Maximum average forward rectified current at $T_L=100^\circ\text{C}$	$I_{(AV)}$	1.0							A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load	$I_{FSM}$	25.0							A
Maximum instantaneous forward voltage at 1.0A	$V_F$	1.1							V
Maximum DC reverse current at rated DC blocking voltage $T_A=25^\circ\text{C}$ $T_A=125^\circ\text{C}$	$I_R$	10.0 50.0							$\mu\text{A}$
Typical junction capacitance	$C_J$	4							pF
Typical thermal resistance	$R_{\theta JA}$	95							$^\circ\text{C/W}$
Operating junction and storage temperature range	$T_J, T_{STG}$	-55 to +150							$^\circ\text{C}$

**Note:** 1. Averaged over any 20ms period.

2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.



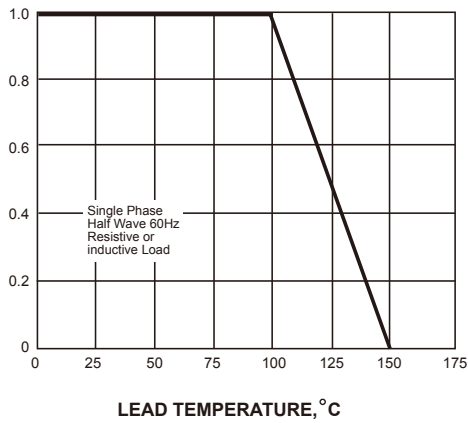


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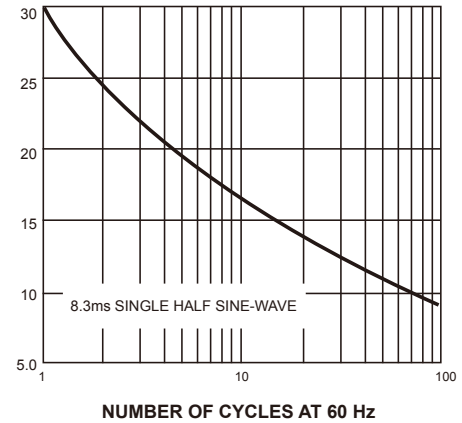
AVERAGE FORWARD RECTIFIED CURRENT,  
AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE



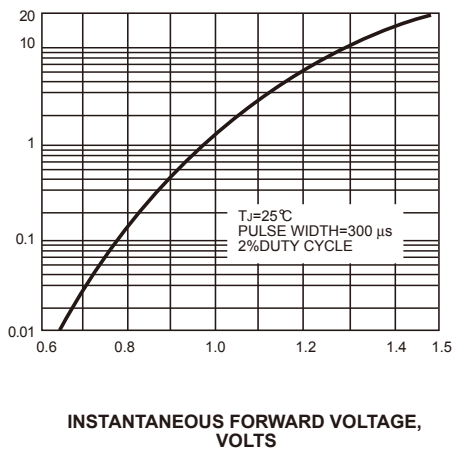
PEAK FORWARD SURGE CURRENT,  
AMPERES

FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT



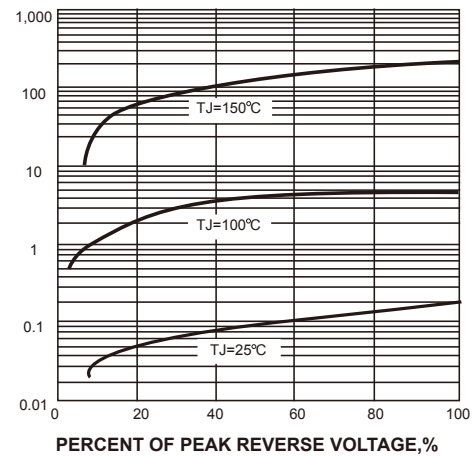
INSTANTANEOUS FORWARD CURRENT, AMPERES

FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



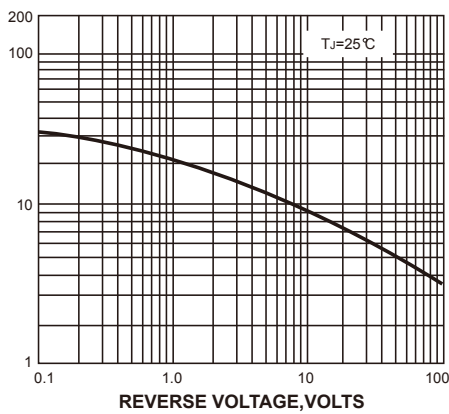
INSTANTANEOUS REVERSE CURRENT,  
MICROAMPERES

FIG. 4-TYPICAL REVERSE CHARACTERISTICS



JUNCTION CAPACITANCE, pF

FIG. 5-TYPICAL JUNCTION CAPACITANCE



TRANSIENT THERMAL IMPEDANCE,  
°C/W

FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE

